

PSMN1R6-30MLH

N-channel 30 V, 1.9 mΩ, 160 A logic level MOSFET in LFPAK33 using NextPowerS3 technology 12 November 2019 Product da

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK33 package. NextPowerS3 technology delivers low R_{DSon} , low I_{DSS} leakage and high efficiency. Rated to 160 A and optimized for DC load switch and hot-swap applications.

2. Features and benefits

- Optimized for low R_{DSon}
- Low leakage < 1 μA at 25 °C
- Low spiking and ringing for low EMI designs
- Optimized for 4.5 V gate drive
- 160 A rated
- High reliability copper-clip bonded and solder die attach LFPAK33 package
- Qualified to 175 °C
- Exposed leads for optimal visual solder inspection

3. Applications

- DC switch / load switch
- USB-PD and fast-charge
- Battery protection
- OR-ing and hot-swap
- Synchronous rectifier in AC-DC and DC-DC applications
- Brushed and BLDC (brushless) motor control

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Oymbol	i diametei				- YP	INIAA	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	30	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	160	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	106	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics			•			
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	1.6	1.9	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 10</u>		-	2	2.6	mΩ
Dynamic ch	naracteristics	•					
Q _{GD}	gate-drain charge	I_D = 25 A; V_{DS} = 15 V; V_{GS} = 4.5 V; Fig. 12; Fig. 13		1.3	7	14	nC

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit			
Q _{G(tot)}	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 12; Fig. 13	18	41	68	nC			
Source-drain	Source-drain diode								
S	softness factor	$I_{S} = 20 \text{ A; } dI_{S}/dt = -100 \text{ A}/\mu\text{s; } V_{GS} = 0 \text{ V;} \\ V_{DS} = 15 \text{ V; } \underline{Fig. 16}$	-	0.7	-				

[1] 160A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D
2	S	source		
3	S	source		G_(i=A)
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK33 (SOT1210)	

6. Ordering information

Table 3. Ordering information

Type number Package					
	Name	Description	Version		
PSMN1R6-30MLH	LFPAK33	Plastic, single ended surface mounted package (LFPAK33); 8 leads; 0.65 mm pitch	SOT1210		

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN1R6-30MLH	1H630L

8. Limiting values

Table 5. Limiting values

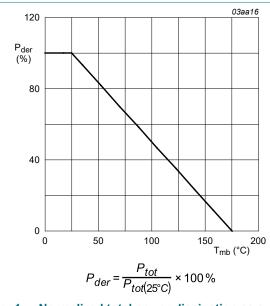
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	30	V
V _{DGR}	drain-gate voltage	$25 \text{ °C} ≤ T_j ≤ 175 \text{ °C}; R_{GS} = 20 kΩ$		-	30	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	106	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	160	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	116	A
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	656	А

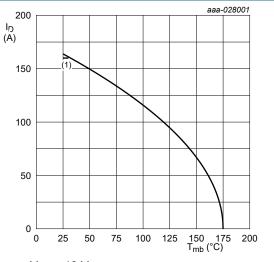
Symbol	Parameter	Conditions		Min	Мах	Unit
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode					
I _S	source current	T _{mb} = 25 °C		-	106	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	656	А
Avalanche ru	uggedness					
E _{DS(AL)S}		$ \begin{array}{l} I_D = 25 \text{ A}; V_{sup} \leq \ 30 \text{ V}; R_{GS} = 50 \ \Omega; \\ V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \ ^\circ\text{C}; unclamped; \\ t_p = 797 \ \mu\text{s} \end{array} $	[2]	-	388	mJ
I _{AS}	non-repetitive avalanche current		[2]	-	87	A

[1] 160A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Protected by 100% test



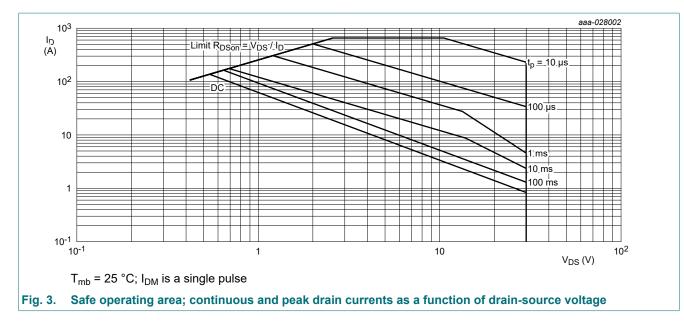




V_{GS} ≥ 10 V

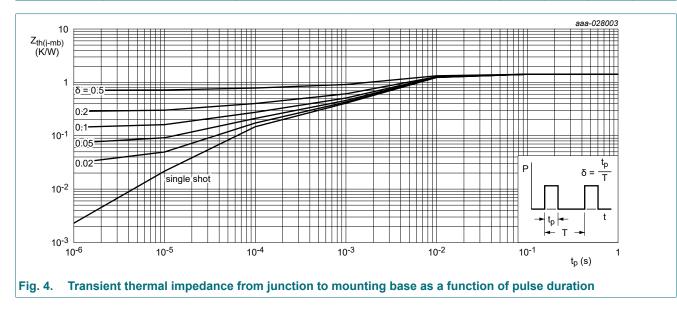
(1) 160A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature



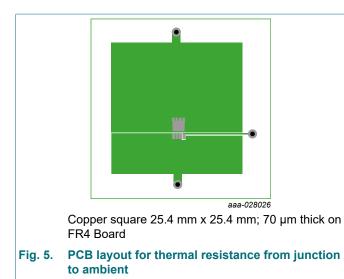
9. Thermal characteristics

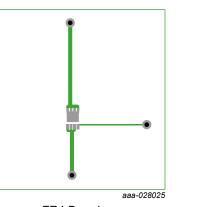
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	1.12	1.42	K/W
R _{th(j-a)}	th _(j-a) thermal resistance from junction to ambient	Fig. 5	-	50	-	K/W
		Fig. 6	-	130	-	K/W



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70 µm copper; FR4 Board

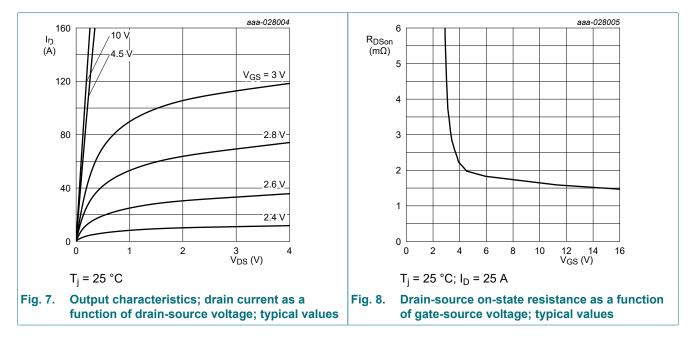
Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

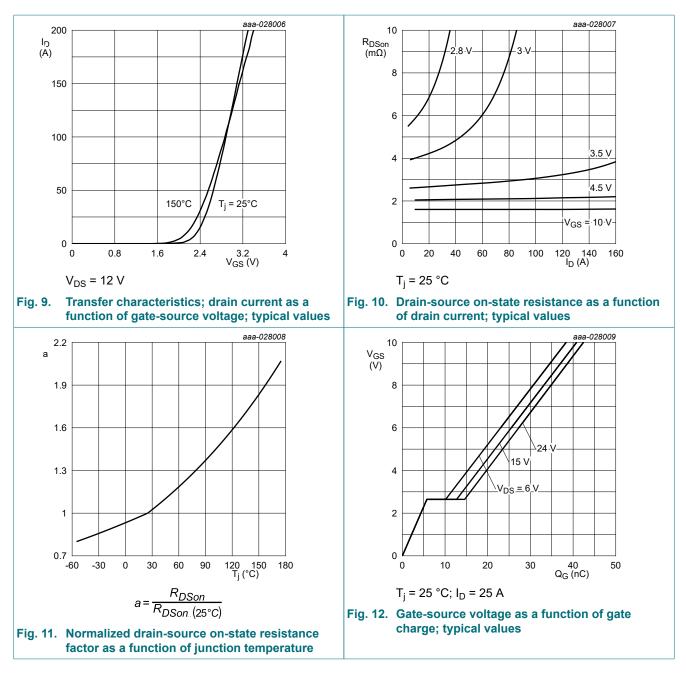
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	27	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C	1.2	1.6	2.2	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-3.8	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 24 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 24 V; V _{GS} = 0 V; T _j = 125 °C	-	2.2	-	μA
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-	1.6	1.9	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	3.5	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-	2	2.6	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	4.8	mΩ
R _G	gate resistance	f = 1 MHz	1.3	3.3	8.3	Ω
Dynamic cha	racteristics	· · ·				
Q _{G(tot)}	total gate charge	$I_{D} = 25 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 4.5 \text{ V};$ Fig. 12; Fig. 13	8.9	20	33	nC
		I_D = 25 A; V_{DS} = 15 V; V_{GS} = 10 V; Fig. 12; Fig. 13	18	41	68	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	21	-	nC

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13		1.5	5.7	11	nC
Q _{GS(th)}	pre-threshold gate- source charge			1	3.6	6.8	nC
Q _{GS(th-pl)}	post-threshold gate- source charge	_		0.6	2.1	4.1	nC
Q _{GD}	gate-drain charge	_		1.3	7	14	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 15 V; <u>Fig. 12</u> ; <u>Fig. 13</u>		-	2.6	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz;		1421	2369	3554	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u> 		455	758	1137	pF
C _{rss}	reverse transfer capacitance			59	217	521	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; R _L = 0.6 Ω; V _{GS} = 4.5 V; R _{G(ext)} = 5 Ω		-	17	-	ns
t _r	rise time			-	34	-	ns
t _{d(off)}	turn-off delay time	_		-	32	-	ns
t _f	fall time	_		-	24	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 15 V; f = 1 MHz; T _j = 25 °C		-	18.7	-	nC
Source-dra	iin diode					_	
V _{SD}	source-drain voltage	I _S = 20 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 15</u>		-	0.8	1	V
t _{rr}	reverse recovery time	$I_{S} = 20 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	28	-	ns
Q _r	recovered charge	V _{DS} = 15 V; <u>Fig. 16</u>	[1]	-	22	-	nC
t _a	reverse recovery rise time	-		-	16.4	-	ns
t _b	reverse recovery fall time			-	11.2	-	ns
S	softness factor			-	0.7	-	

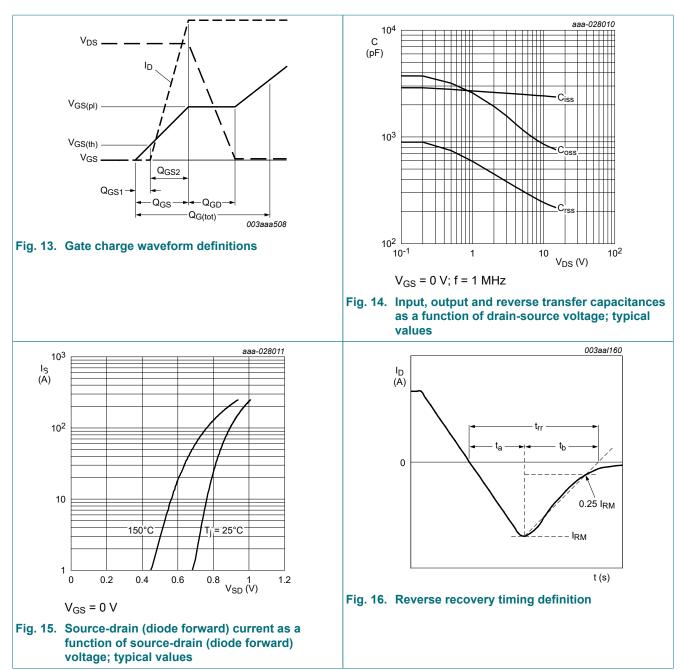
[1] includes capacitive recovery





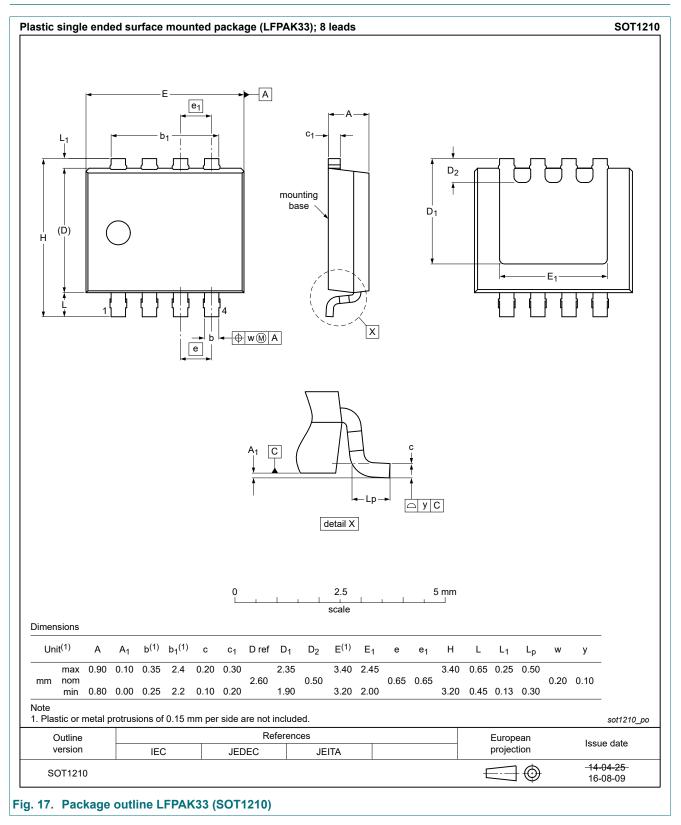
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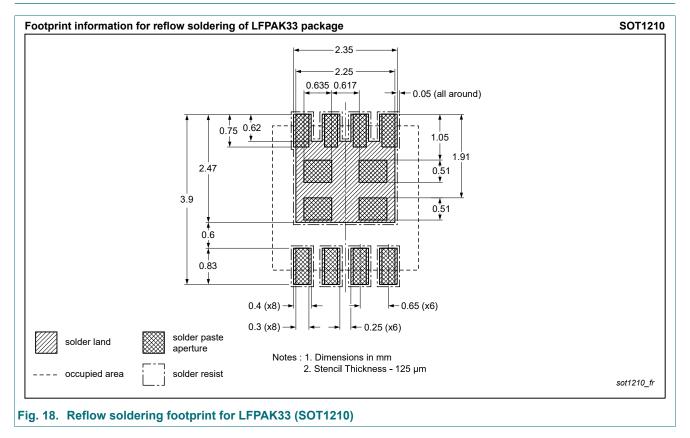


Product data sheet

11. Package outline



12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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